



44 FARRAND STREET  
BLOOMFIELD, NJ 07003  
(973) 748-5089  
<http://www.nteinc.com>

## NTE166 thru NTE170 Single Phase Bridge Rectifier 2.0 Amp

### **Features:**

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- Ideal for Printed Circuit Board

**Maximum Ratings and Electrical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified. Single Phase, Half Wave, 60Hz, Resistive or Inductive Load. For Capacitive Load, Derate Current by 20%)

Peak Repetitive Reverse Voltage,  $V_{RRM}$

NTE166 .....	100V
NTE167 .....	200V
NTE168 .....	400V
NTE169 .....	600V
NTE170 .....	1000V

Working Peak Reverse Voltage,  $V_{RWM}$

NTE166 .....	100V
NTE167 .....	200V
NTE168 .....	400V
NTE169 .....	600V
NTE170 .....	1000V

DC Blocking Voltage,  $V_R$

NTE166 .....	100V
NTE167 .....	200V
NTE168 .....	400V
NTE169 .....	600V
NTE170 .....	1000V

RMS Reverse Voltage,  $V_R(\text{RMS})$

NTE166 .....	70V
NTE167 .....	140V
NTE168 .....	280V
NTE169 .....	420V
NTE170 .....	700V

Average Rectified Output Current ( $T_A = +50^\circ\text{C}$ , Note 1),  $I_O$  ..... 2A

Peak Forward Surge Current,  $I_{FSM}$   
(8.3ms Single Sine-Wave Superimposed on Rated Load) ..... 60A

Forward Voltage Drop (Per Bridge Element,  $I_F = 2\text{A}$ ),  $V_{FM}$  ..... 1.1V

Note 1. Leads maintained at ambient temperature at a distance of 9.5mm from case.

**Maximum Ratings and Electrical Characteristics (Cont'd):** ( $T_A = +25^\circ\text{C}$  unless otherwise specified.  
Single Phase, Half Wave, 60Hz, Resistive or Inductive Load. For Capacitive Load, Derate Current by 20%)  
Maximum Reverse Current (at Rated DC Blocking Voltage),  $I_{RM}$

$T_A = +25^\circ\text{C}$ .....	10 $\mu\text{A}$
$T_A = +100^\circ\text{C}$ .....	500 $\mu\text{A}$
Rating for Fusing ( $t < 8.3\text{ms}$ ), $I^2t$ .....	15A <sup>2</sup> s
Typical Junction Capacitance (Per Element, Note 2), $C_j$ .....	25pF
Typical Thermal Resistance, Junction-to-Ambient (Note 3), $R_{thJA}$ .....	30K/W
Operating Junction Temperature Range, $T_J$ .....	-55° to +165°C
Storage Temperature Range, $T_{stg}$ .....	-55° to +165°C

Note 2. Measured at 1.0MHz and applied reverse voltage of 4VDC.

Note 3. Thermal resistance junction-to-ambient mounted on a PC board with 12mm<sup>2</sup> copper pad.

